

Form PTO 1449 (Modified)		U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		ATTY DOCKET NO. 249930US2S DIV		SERIAL NO. 10/796,061 New Div. Application	
LIST OF REFERENCES CITED BY APPLICANT				APPLICANT Yoshiaki ASAO			
				FILING DATE HEREWITH		GROUP 2818	
U.S. PATENT DOCUMENTS							
EXAMINER INITIAL	CLASS	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
TH	AA	6,417,561	07-2002	TUTTLE	257	659	—
	AB	6,525,957	02-2003	GORONKIN ET AL	365	158	—
	AC	6,174,737	01/16/2001	DURLAM ET AL	438	3	—
TH	AD	6,211,090	04/03/2001	DURLAM ET AL	438	692	—
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						
	AL						
	AM						
	AN						
FOREIGN PATENT DOCUMENTS							
		DOCUMENT NUMBER	DATE	COUNTRY	TRANSLATION YES NO		
	AO						
	AP						
	AQ						
	AR						
	AS						
	AT						
	AU						
	AV						
OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, etc.)							
TH	AW	R. SCHEUERLEIN, et al., ISSCC 2000/Session 7/ TD: Emerging Memory Device and Technologies/Paper TA 7.2, pgs. 128-129, 94-95, 409-410, "A 10ns READ AND WRITE NON-VOLATILE MEMORY ARRAY USING A MAGNETIC TUNNEL JUNCTION AND FET SWITCH IN EACH CELL", 2000.					
	AX						
	AY						
	AZ					<input type="checkbox"/> Additional References sheet(s) attached	
Examiner TH - TH HIO					Date Considered July 2004		
*Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.							